Similarly, we can sum the amplitudes of all the reflection paths.

$$r_{31} = r_{21} + t'_{21}r_{32}[1 + r'_{21}r_{32} + (r'_{21}r_{32})^2 + \cdots]t_{21}$$
  
=  $r_{21} + t'_{21}r_{32}(1 - r'_{21}r_{32})^{-1}t_{21}$ 

 $t'_{31}$  and  $r'_{31}$  can also be obtained in a similar manner by starting with a wave incident from the right rather than from the left.

1.4 Tunneling: Consider the structure in Fig. 1.7 but with an electron energy E that is less than  $E_{C2}$  ( $E_{C1} < E < E_{C2}$ ). Assume  $k_x = k_y = 0$ . It is apparent from eq. (1.62) that  $k_2$  is imaginary. Derive an expression for  $T_B$ .

Solution:

$$k_{1} = \sqrt{\frac{2m*(E - E_{C1})}{\hbar^{2}}}$$

$$k_{2} = i\gamma$$

$$\gamma = \sqrt{\frac{2m*(E_{C2} - E)}{\hbar^{2}}}$$

From eq. (1.66), using eqs. (1.43), (1.48), and (1.49),

$$t_{\rm B} = \frac{i4k_1\gamma e^{-\gamma d}}{(k_1 + i\gamma)^2 - (k_1 - i\gamma)^2 e^{-2\gamma d}}$$

$$= \frac{i2k_1\gamma}{(k_1^2 - \gamma^2)\sinh\gamma d + i2k_1\gamma\cosh\gamma d}$$
(1.77)

Hence,

$$T_{\rm B} = |t_{\rm B}|^2 = \frac{4k_1^2 \gamma^2}{4k_1^2 \gamma^2 + (k_1^2 + \gamma^2)^2 \sinh^2 \gamma d}$$

$$= \frac{1}{1 + \frac{(E_{\rm C2} - E_{\rm C1})^2 \sinh^2 \gamma d}{4(E - E_{\rm C1})(E_{\rm C2} - E)}}$$

$$\approx \frac{4(E - E_{\rm C1})(E_{\rm C2} - E)}{(E_{\rm C2} - E_{\rm C1})^2} e^{-2\gamma d}, \quad \text{if } \gamma d \gg 1 \quad (1.78b)$$

It is straightforward to calculate the reflection coefficient  $r_{\rm B}$  from eq. (1.67), using eqs. (1.43), (1.48), and (1.49).

$$r_{\rm B} = \frac{(k_1^2 + \gamma^2)(1 - e^{-2\gamma d})}{(k_1 + i\gamma)^2 - (k_1 - i\gamma)^2 e^{-2\gamma d}}$$

$$= \frac{(k_1^2 + \gamma^2)\sinh \gamma d}{(k_1^2 - \gamma^2)\sinh \gamma d + i2k_1\gamma\cosh \gamma d}$$
(1.79)

Hence,

$$R_{\rm B} = |r_{\rm B}|^2 = \frac{(k_1^2 + \gamma^2)^2 \sinh^2 \gamma d}{4k_1^2 \gamma^2 + (k_1^2 + \gamma^2)^2 \sinh^2 \gamma d}$$
(1.80)

It is easy to check that  $R_{\rm B}+T_{\rm B}=1$ . Also, it can be shown that  $t_{\rm B}'=t_{\rm B}$  and  $r_{\rm B}'=r_{\rm B}$ ; this is expected from the symmetry of the structure.

It is apparent from eq. (1.78) that there is a non-zero probability for an electron to transmit through a barrier if it is thin enough, that is, if  $\gamma d$  is small enough. This is a quantum mechanical phenomenon known as tunneling, not predicted by Newton's law. From a particle point of view,  $T_{\rm B}=0$  regardless of the barrier thickness "d" as long as  $E < E_{\rm C2}$ . But from a wave point of view, when  $E < E_{\rm C2}$  the wave becomes decaying (or evanescent) rather than propagating within the barrier. If the barrier ends before the wave has attenuated sufficiently—that is, if  $\gamma d \lesssim 1$ —then it can transmit significantly through the barrier. This phenomenon of tunneling has found extensive applications in both basic and applied sciences (Ref. [1.3]). A recent application is the Scanning Tunneling Microscope that makes it possible to get very high-resolution images of surfaces by exploiting the exponential dependence of the tunneling current on the barrier thickness "d".

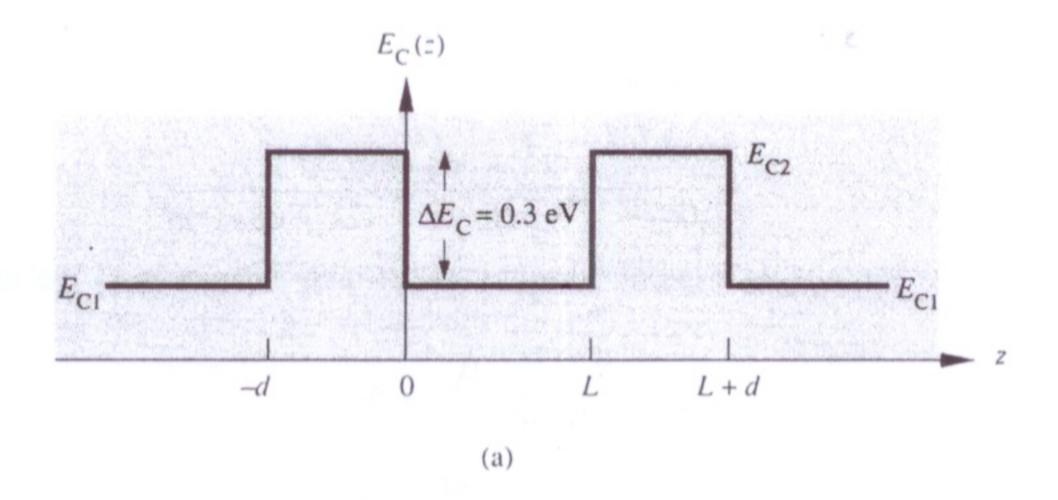
1.5 Resonant Tunneling: Consider the double barrier structure shown in Fig. 1.11a. We have already calculated the transmission coefficient  $t_{\rm B}$  and the reflection coefficient  $r_{\rm B}$  for a single barrier (Exercise 1.4). Assuming that the two barriers are identical, show that the overall transmission coefficient  $t_{\rm B}$  through the double barrier structure is given by

$$t_{2B} = \frac{t_B^2 e^{ik_1 L}}{1 - r_B^2 e^{i2k_1 L}}$$

so that

$$T_{2B} = |t_{2B}|^2 = \left[1 + \frac{4R_B}{T_B^2} \sin^2(k_1 L - \theta)\right]^{-1}$$
 (1.81)

where  $r_{\rm B}^2 = R_{\rm B} e^{-i2\theta}$ ,  $|t_{\rm B}|^2 = T_{\rm B}$ . Plot  $T_{\rm B}$  and  $T_{\rm 2B}$  as a function of electron energy E in the range  $E_{\rm C1} < E < E_{\rm C1} + 0.3$  eV assuming that  $E_{\rm C2} = E_{\rm C1} + 0.3$  eV, d = 40 Å, L = 100 Å,  $m^* = 0.07$   $m_0$ .



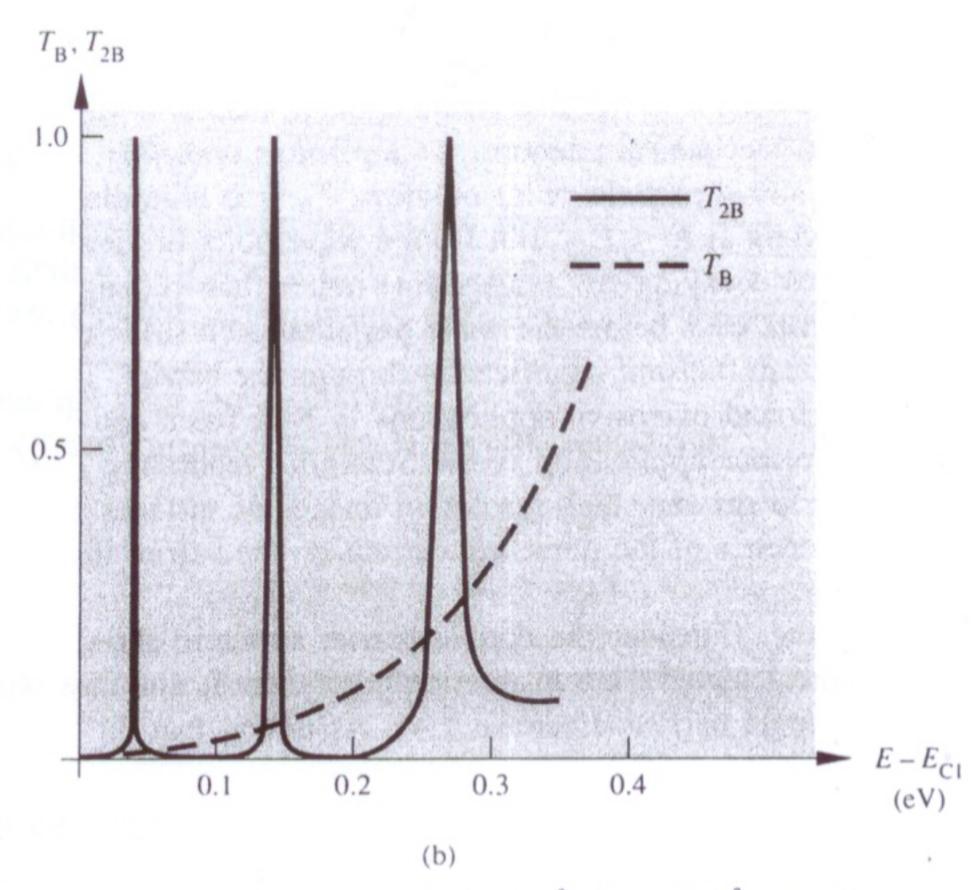


Fig. 1.11 The resonant tunneling device (d = 40 Å, L = 100 Å). (a)  $E_C(z)$  vs. z; (b)  $T_B(E)$ ,  $T_{2B}(E)$ .

## Solution:

Earlier we derived  $t_B$  [eq. (1.66)] by cascading the scattering matrices for two potential steps and a free propagation region in between.  $t_{2B}$  is derived by cascading the scattering matrices for two barriers and a free propagation region in the same manner.

Figure 1.11b shows plots of  $T_{\rm B}$  and  $T_{\rm 2B}$  as a function of the electron energy E. It is interesting to note how an electron with energy  $E \simeq 0.035$  eV has a very low probability of getting through a single barrier ( $T_{\rm B} \simeq 0$ ) but can go clean through

two barriers ( $T_{2B} \approx 1$ ). This behavior is very hard to rationalize with a particle-like picture. This phenomenon is known as resonant tunneling and has received considerable attention lately as a high-frequency negative-differential resistance device (Ref. [1.4]).

1.6 What is the probability current density  $J_z$  for a single electron with a wavefunction given by

$$\Psi(z,t) = (e^{-\gamma z} + ae^{+\gamma z})e^{-iEt/\hbar}$$

where  $\gamma = \kappa - ik$ ,  $\kappa$  and k being real numbers.

Solution:

$$\left(\frac{\partial \Psi}{\partial z}\right)^* = (-\gamma^* e^{-\gamma^* z} + \gamma^* a^* e^{+\gamma^* z}) e^{iEt/\hbar}$$

Hence,

$$\left(\frac{\partial \Psi}{\partial z}\right)^* \Psi = -\gamma^* e^{-(\gamma + \gamma^*)z} + \gamma^* |a|^2 e^{(\gamma + \gamma^*)z} + \gamma^* a^* e^{-(\gamma - \gamma^*)z} - \gamma^* a e^{(\gamma - \gamma^*)z}$$

From eq. (1.10),

$$J_{z} = -\frac{iq\hbar}{2m^{*}} \left[ \left( \frac{\partial \Psi}{\partial z} \right)^{*} \Psi - \text{complex conjugate} \right]$$

$$= \frac{-q\hbar k}{m^{*}} (e^{-2\kappa z} - |a|^{2} e^{2\kappa z}) + \frac{iq\hbar \kappa}{m^{*}} (ae^{-i2kz} - a^{*} e^{i2kz})$$

$$= \frac{q\hbar k}{m^{*}} (1 - |a|^{2}) \quad \text{if } \kappa = 0$$

$$\frac{iq\hbar \kappa}{m^{*}} (a - a^{*}) \quad \text{if } k = 0$$

When  $\kappa = 0$ , the net current is simply the difference between that carried by the forward wave ( $\sim e^{ikz}$ ) and that carried by the reverse wave ( $\sim e^{-ikz}$ ). It is interesting to note that this is not true if  $\kappa \neq 0$ . The current carried by a decaying wavefunction ( $\sim e^{-\kappa z}$ ) or a growing wavefunction ( $\sim e^{+\kappa z}$ ) is individually zero. But a linear combination of the two (as in a tunnel barrier, Exercise 1.4) carries a current proportional to Im(a).